TOSHIBA RECTIFIER SILICON DIFFUSED TYPE

CMC01

For Strobe Discharge Circuit

• Repetitive peak reverse voltage: $V_{RRM} = 400 \text{ V}$

• Average forward current: $I_{F(AV)} = 1.0 A$

 Repetitive peak forward current: I_{FRM} = 150 A (Refer to the Note 2)

• Small surface-mount package

"M-FLAT TM " (Toshiba package name)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Repetitive peak reverse voltage	V_{RRM}	400 V	
Average forward current (NOTE1)	I _{F (AV)}	1.0(Ta=47°C)	Α
Peak one cycle surge forward current (non-repetitive)	I _{FSM}	30 (50 Hz)	Α
Repetitive peak forward current (NOTE2)	I _{FRM}	150	А
Junction temperature	Tj	-40 ~ 150	°C
Storage temperature range	T _{stg}	-40 ~ 150	°C

Note1: Device mounted on a glass-epoxy board

board size: $50 \text{ mm} \times 50 \text{ mm}$ soldering land: $6 \text{ mm} \times 6 \text{ mm}$ glass-epoxy board thickness 1.6t Unit: mm

2
2
1,75±0,1
2,4±0,1

1 ANODE
2 CATHODE

DEDEC

JEITA

TOSHIBA

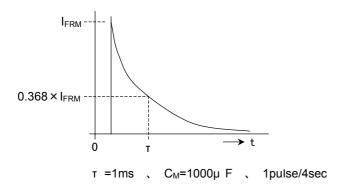
3-4E1A

Weight: 0.023 g (typ.)

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Peak forward voltage	V _{FM}	I _{FM} = 1.0 A (Pulse test)	_	0.86	1.0	V
Repetitive peak reverse current	I _{RRM}	V _{RRM} = 400 V (Pulse test)	_	_	10	μA
Thermal resistance		Device mounted on a ceramic board Board size: 50 mm × 50 mm Soldering land: 2 mm × 2 mm Ceramic board thickness: 0.64t	_	_	110	°C/W
	R _{th (j-a)}	Device mounted on a glass-epoxy board Board size: 50 mm × 50 mm Soldering land: 6 mm × 6 mm glass-epoxy board thickness: 1.6t	_			
		Device mounted on a glass-epoxy board Board size: 50 mm × 50 mm Soldering land: 2.1 mm ×1.4 mm glass-epoxy board thickness: 1.6t			180	
	R _{th (j-l)}	_			16	°C/W

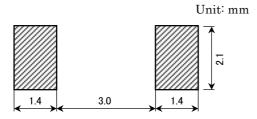
Note 2 Repetitive peak forward current waveform



Marking

Abbreviation Code	Part No.		
C1	CMC01		

Standard Soldering Pad



2 2004-07-01

Handling Precaution

The maximum ratings denote the absolute maximum ratings, which are rated values and must not be exceeded during operation, even for an instant. The following are the general derating methods that we recommend when you design a circuit with a device.

 V_{RRM} : We recommend that the worst case voltage, including surge voltage, be no greater than 80% of the maximum rating of V_{RRM} for a DC circuit and be no greater than 50% of that of V_{RRM} for an AC circuit. V_{RRM} has a temperature coefficient of 0.1%/ . Take this temperature coefficient into account designing a device at low temperature.

I_{F(AV)}: We recommend that the worst case current be no greater than 80% of the maximum rating of I_{F(AV)}. Carry out adequate heat design. If you can't design a circuit with excellent heat radiation, please set the margin by using an allowable Tamax-I_F(AV) curve.

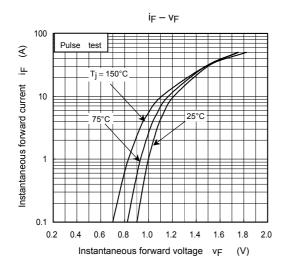
This rating is only applied for a strobe flash circuit. We recommend that the worst case current be controlled less than the maximum rating of I_{FRM}. The total number of repetitive currents must be less than 5000 times within the lifespan of the device.

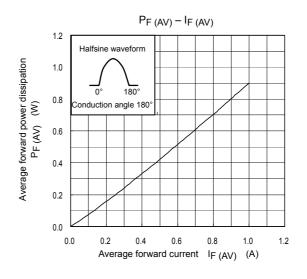
This rating specifies the non-repetitive peak current in one cycle of a 50-Hz sine wave, condition angle 180. Therefore, this is only applied for an abnormal operation, which seldom occurs during the lifespan of the device.

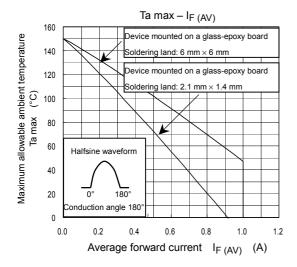
We recommend that a device be used at a Tj of below 120 under the worst load and heat radiation conditions.

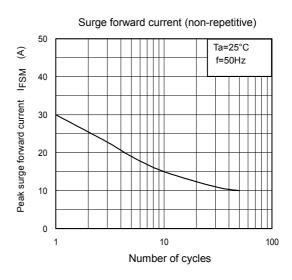
Thermal resistance between junction and ambient fluctuates depending on the device's mounting condition. When using a device, design a circuit board and a soldering land size to match the appropriate thermal resistance value.

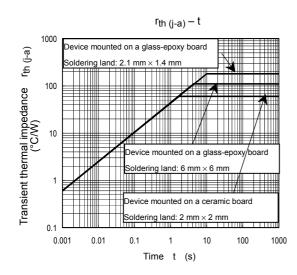
Please refer to the Rectifiers databook for further information.











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